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| FORM PTO-1449 INFORMATION DISCLOSURE STATEMENT | | | | Attorney ref.: | Application serial No.: | | |
| | | | | AI 411NP | 10/577,360 | | |
| | | | | Applicant(s): Masaru TAKAISHI | | | |
| | | | | Filing date: | Group art unit: | | |
| | | | | April 28, 2006 | 2811 2818 | | |
| US PATENT DOCUMENTS | | | | | | | |
| Examiner Initial | | Document Number | Date | Name | Class | Sub-Class | Filing Date |
| /HQH/ | AA | US-6,413,822 B2 | 07-02-2002 | Williams et al. | | | |
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| Examiner Initial | | Document Number | Date | Country | Class | Sub-Class | Translation |
| /HQH/ | AB | 2003-92386 | 03-28-2003 | JAPAN | | | Abstract and translation |
| /HQH/ | AC | EP 1 168 455 A2 | 01-02-2002 | EUROPE | | | N/a |
| OTHER (Including Author, Title, Date, Pertinent Pages, etc.) | | | | | | | |
| /HQH/ | AD | SAGGIO M ET AL: "MDMESH TM : INNOVATIVE TECHNOLOGY FOR HIGH VOLTAGE POWERMOSFETS" PROCEEDINGS OF THE INTERNATIONAL SYMPOSIUM ON POWERSEMICONDUCTOR DEVICES AND ICS, NEW YORK, NY, US, 22 May 2000 (2000-05-22), pages 65-68, XP000985371 | | | | | |
| Examiner: /Hoang Quan Ho/ | | | | | Date Considered: 02/02/2009 | | |
| EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant. | | | | | | | |